FAIRCHILD

SEMICONDUCTOR

CD4029BC Presettable Binary/Decade Up/Down Counter

General Description

The CD4029BC is a presettable up/down counter which counts in either binary or decade mode depending on the voltage level applied at binary/decade input. When binary/ decade is at logical "1", the counter counts in binary, otherwise it counts in decade. Similarly, the counter counts up when the up/down input is at logical "1" and vice versa.

A logical "1" preset enable signal allows information at the "jam" inputs to preset the counter to any state asynchronously with the clock. The counter is advanced one count at the positive-going edge of the clock if the carry in and preset enable inputs are at logical "0". Advancement is inhibited when either or both of these two inputs is at logical "1". The carry out signal is normally at logical "1" state and goes to logical "0" state when the counter reaches its maximum count in the "up" mode or the minimum count in the "down" mode provided the carry input is at logical "0" state.

All inputs are protected against static discharge by diode clamps to both V_{DD} and $V_{SS}.$

Features

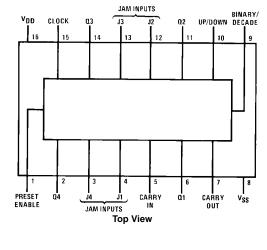
- Wide supply voltage range: 3V to 15V
- High noise immunity: 0.45 V_{DD} (typ.)
- Low power TTL compatibility: fan out of 2 driving 74L or 1 driving 74LS
- Parallel jam inputs
- Binary or BCD decade up/down counting

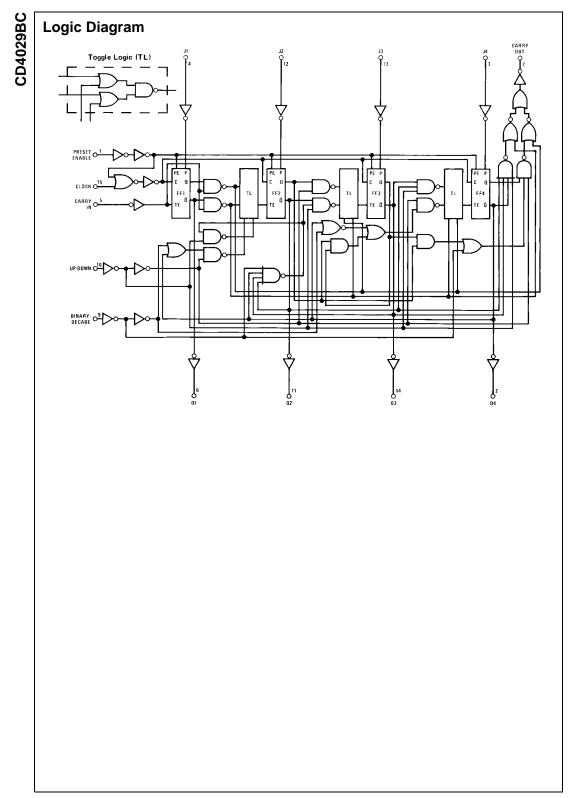
Ordering Code:

Order Number	Package Number	Package Description
CD4029BCWM	M16B	16-Lead Small Outline Intergrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
CD4029BCSJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
CD4029BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram





Absolute Maximum Ratings(Note 1)

(Note 2)

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V _{DD})	-0.5V to +18 V _{DC}
Input Voltage (V _{IN})	–0.5V to V_{DD} + 0.5 V_{DC}
Storage Temperature Range (T_S)	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Lead Temperature (TL)	
(Soldering, 10 seconds)	260°C

DC Supply Voltage (V_{DD})

Input Voltage (VIN)

3V to 15 V_{DC} 0V to V_{DD} V_{DC} $-55^{\circ}C$ to $+125^{\circ}C$

Operating Temperature Range (T_A)

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Tempera-ture Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides

conditions for actual device operation. Note 2: $V_{SS} = 0V$ unless otherwise specified.

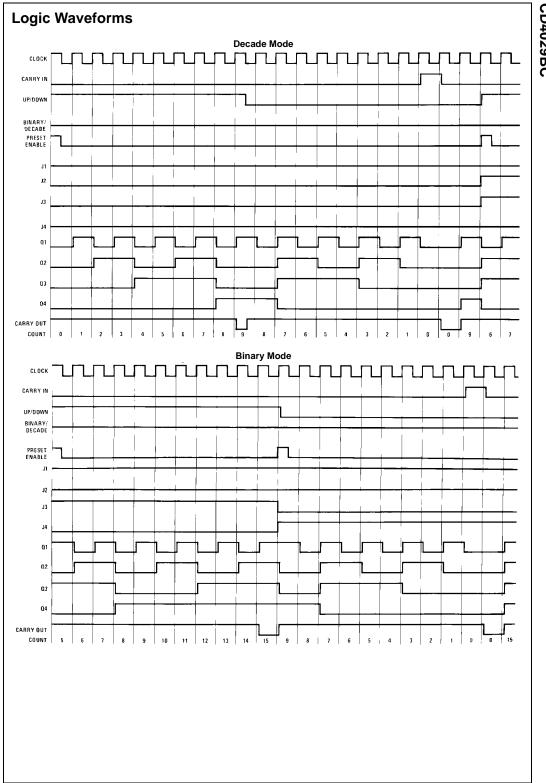
Symbol	Parameter	Conditions	–55°C		+25°C			+125°C		Units
Symbol	Parameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device Current	$V_{DD} = 5V$		5			5		150	
		$V_{DD} = 10V$		10			10		300	μA
		$V_{DD} = 15V$		20			20		600	
V _{OL}	LOW Level	I _O < 1 μA								
	Output Voltage	$V_{DD} = 5V$		0.05		0	0.05		0.05	
		$V_{DD} = 10V$		0.05		0	0.05		0.05	V
		$V_{DD} = 15V$		0.05		0	0.05		0.05	
V _{OH}	HIGH Level	I _O < 1 μA	ο < 1 μΑ							
	Output Voltage	$V_{DD} = 5V$	4.95		4.95	5		4.95		
		$V_{DD} = 10V$	9.95		9.95	10		9.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		
VIL	LOW Level	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$	V _O = 0.5V or 4.5V 1.5 1.5		1.5					
	Input Voltage	$V_{DD} = 10V$, $V_O = 1V$ or $9V$		3.0			3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$		4.0			4.0		4.0	
VIH	HIGH Level	$V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$	3.5		3.5			3.5		
	Input Voltage	$V_{DD} = 10V$, $V_O = 1V$ or $9V$	7.0		7.0			7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V \text{ or } 13.5V$	11.0		11.0			11.0		
I _{OL}	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.64		0.51	0.88		0.36		
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	4.2		3.4	8.8		2.4		
I _{OH}	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.64		-0.51	-0.88		-0.36		
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-4.2		-3.4	-8.8		-2.4		
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.1		-10 ⁻⁵	-0.1		-1.0	μA
		$V_{DD} = 15V, V_{IN} = 15V$		0.1		10 ⁻⁵	0.1		1.0	μΛ

DC Electrical Characteristics (Note 2)

Note 3: I_{OH} and I_{OL} are tested one output at a time.

$T_{A} = 25 \text{ C}, \text{ C}_{L} =$	= 50 pF, $R_L = 200k$, Input $t_{rCL} = t_{fC}$	L = 20 ns, unless otherwise specifie	d			
Symbol	Parameter	Conditions	Min	Тур	Max	U
CLOCKED OPER/	ATION					
t _{PHL} or t _{PLH}	Propagation Delay Time	$V_{DD} = 5V$		200	400	
	to Q Outputs	$V_{DD} = 10V$		85	170	
		$V_{DD} = 15V$		70	140	
t _{PHL} or t _{PLH}	Propagation Delay Time	$V_{DD} = 5V$		320	640	
	to Carry Output	$V_{DD} = 10V$		135	270	
		$V_{DD} = 15V$		110	220	
t _{PHL} or t _{PLH}	Propagation Delay Time	C _L = 15 pF				
	to Carry Output	$V_{DD} = 5V$		285	570	
		$V_{DD} = 10V$		120	240	
		$V_{DD} = 15V$		95	190	
t _{THL} or t _{TLH}	Transition Time/Q	$V_{DD} = 5V$		100	200	
	or Carry Output	$V_{DD} = 10V$		50	100	
		V _{DD} = 15V		40	80	
t _{WH} or t _{WL}	Minimum Clock	$V_{DD} = 5V$		160	320	
	Pulse Width	$V_{DD} = 10V$		70	135	
		$V_{DD} = 15V$		55	110	
t _{rCL} or t _{fCL}	Maximum Clock Rise	$V_{DD} = 5V$	15			
102 102	and Fall Time	$V_{DD} = 10V$	10			
		V _{DD} = 15V	5			
t _{SU}	Minimum Set-Up Time	$V_{DD} = 5V$		180	360	
00		$V_{DD} = 10V$		70	140	
		V _{DD} = 15V		55	110	
f _{CL}	Maximum Clock Frequency	$V_{DD} = 5V$	1.5	3.1		
0L		$V_{DD} = 10V$	3.7	7.4		N
		V _{DD} = 15V	4.5	9		
C _{IN}	Average Input Capacitance	Any Input		5	7.5	
C _{PD}	Power Dissipation Capacitance	Per Package (Note 5)		65	-	
PRESET ENABLE		ů ()				
t _{PHL} or t _{PLH}	Propagation Delay Time	$V_{DD} = 5V$		285	570	1
	to Q output	$V_{DD} = 10V$		115	230	
		V _{DD} = 15V		95	195	
t _{PHL} or t _{PLH}	Propagation Delay Time	$V_{DD} = 5V$		400	800	
-FHL FLH	to Carry Output	$V_{DD} = 10V$		165	330	
		$V_{DD} = 15V$		135	260	
t _{WH}	Minimum Preset Enable	$V_{DD} = 5V$		80	160	
-	Pulse Width	$V_{DD} = 10V$		30	60	
		$V_{DD} = 15V$		25	50	
t _{REM}	Minimum Preset Enable	$V_{DD} = 5V$		150	300	+
'REM	Removal Time	$V_{DD} = 10V$		60	120	
		$V_{DD} = 15V$ $V_{DD} = 15V$		50	100	
CARRY INPUT OF	PERATION	· · · · · · · · · · · · · · · · · · ·		50	100	L
t _{PHL} or t _{PLH}	Propagation Delay Time	$V_{DD} = 5V$		265	530	T
PHL . PLH	to Carry Output	$V_{DD} = 3V$ $V_{DD} = 10V$		110	220	
		$V_{DD} = 10V$ $V_{DD} = 15V$		90	180	
tour tour	Propagation Delay Time	$C_L = 15 \text{pF}$			100	-
t _{PHL} , t _{PLH}	to Carry Output	$V_{DD} = 5V$		200	400	
	to Carry Output	$V_{DD} = 3V$ $V_{DD} = 10V$		85	170	

Note 4: *AC Parameters are guaranteed by DC correlated testing. Note 5: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation, see 74C Family Characteristics application note, AN-90.



CD4029BC

